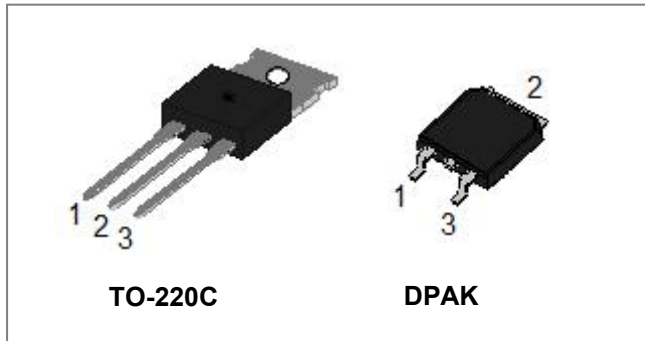
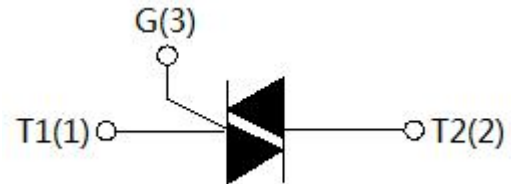


SST136 Series 4A TRIACs



Circuit Diagram



Description

With low holding and latching current, SST136 series triacs are especially recommended for use on middle and small resistance type power load. From all three terminals to external heatsink.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Storage junction temperature range	T_{stg}	-	-40-150	°C
Operating junction temperature range	T_j	-	-40-125	°C
Repetitive peak off-state voltage($T_j=25^\circ\text{C}$)	V_{DRM}	-	600/800	V
Repetitive peak reverse voltage($T_j=25^\circ\text{C}$)	V_{RRM}	-	600/800	V
Non repetitive surge peak Off-state voltage	V_{DSM}	-	$V_{DRM} + 100$	V
Non repetitive peak reverse voltage	V_{RSM}	-	$V_{RRM} + 100$	V
RMS on-state current	$I_{(TRMS)}$	TO-252-4R ($T_c=100^\circ\text{C}$)	4	A
		TO-220C($T_c=107^\circ\text{C}$)		
Non repetitive surge peak on-state current (full cycle, $F=50\text{Hz}$)	I_{TSM}	-	35	A
I^2t value for fusing ($t_p=10\text{ms}$)	I^2t	-	6.1	A^2s
Critical rate of rise of on-state current ($I_G = 2 \times I_{GT}$)	di/dt	I - II - III	50	A/ μs
		IV	10	
Peak gate current	I_{GM}	-	2	A
Average gate power dissipation	P_{GM}	-	0.5	W
Peak gate power	$P_{G(AV)}$	-	5	W

Electrical Characteristics($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Test Condition	Quadrant	Value				Unit	
			T	D	E	F		
I_{GT}	$V_D=12\text{V}$	I - II - III	MAX	5	5	10	25	mA
		IV		5	10	25	70	
V_{GT}		ALL	MAX	1.3				V
V_{GD}	$V_D=V_{DRM}$ $T_j=125^\circ\text{C}$ $R_L=3.3\text{K}\Omega$	ALL	MIN	0.2				V
I_L	$I_G=1.2I_{GT}$	I - III	MAX	10	20	30	40	mA
		II - IV		15	35	45	60	
I_H	$I_T=100\text{mA}$		MAX	5	15	25	30	mA
dV/dt	$V_D=2/3V_{DRM}$ Gate Open $T_j=125^\circ\text{C}$		MIN	10	20	50	50	V/ μs
(dV/dt)c	(dI/dt)c=1.7A/ms $T_j=125^\circ\text{C}$		MIN	0.1	0.1	0.5	5	V/ μs

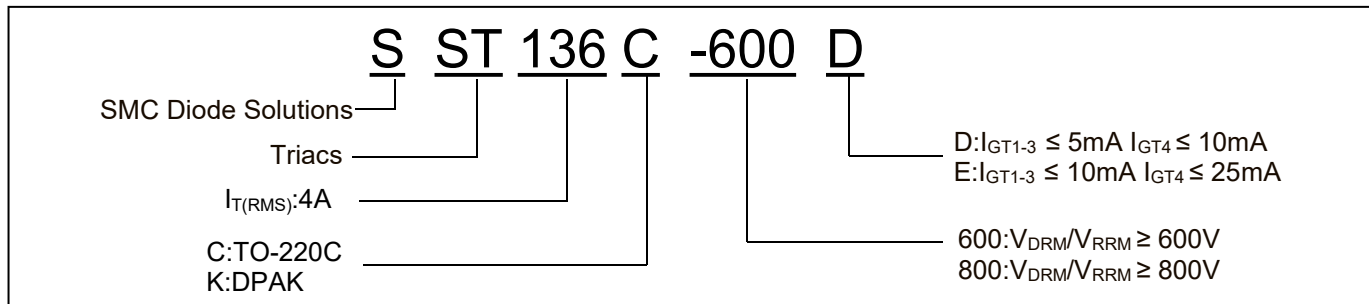
Static Characteristics

Symbol	Condition	Max.	Units
V_{TM}	$I_T=5.5\text{A}$ $t_p=380\mu\text{s}$, $T_j=25^\circ\text{C}$	1.6	V
I_{DRM}	$V_D=V_{DRM}$ $V_R=V_{RRM}$, $T_j=25^\circ\text{C}$	5	μA
I_{RRM}	$V_D=V_{DRM}$ $V_R=V_{RRM}$, $T_j=125^\circ\text{C}$	0.5	mA

Thermal Resistances

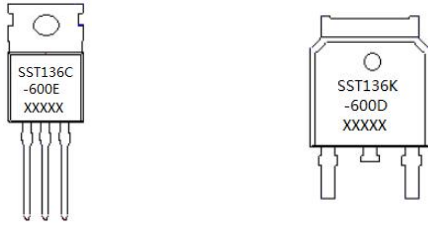
Symbol	Condition	Value	Units
$R_{th(j-c)}$	Junction to case(AC)	TO-220C	2.5
		DPAK	2.8

Ordering Information



Device	Package	Shipping
SST136 Series	TO-220C	50pcs/ Tube
SST136 Series	DPAK	2500pcs/ Reel
SST136 Series TR	DPAK	2500pcs/ Reel

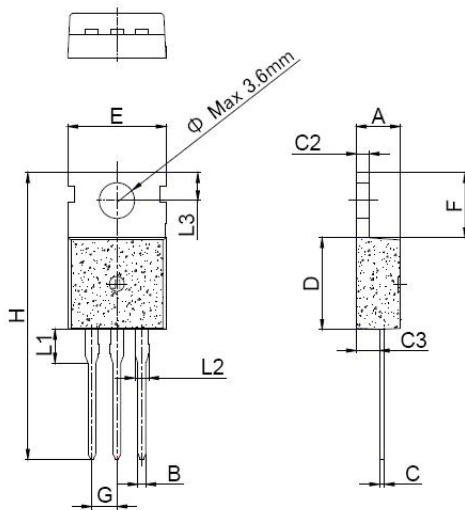
Marking Diagram



Where XXXXX is YYWWL

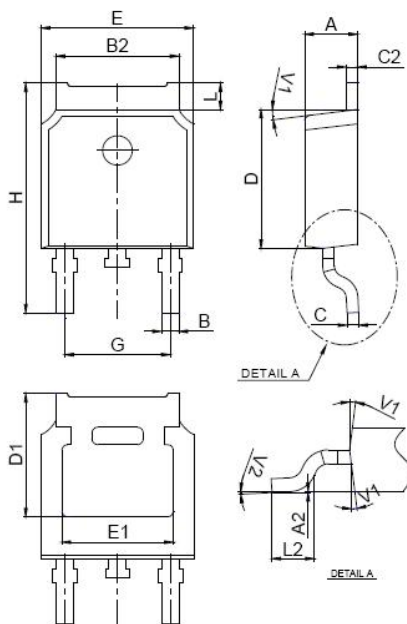
SST136C-600E = Part name
SST136K-600D = Part name
YY = Year
WW = Week
L = Lot Number

Mechanical Dimensions TO-220C



SYMBOL	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.70		0.90	0.028		0.035
C	0.45		0.60	0.018		0.024
C2	1.23		1.32	0.048		0.052
C3	2.20		2.60	0.087		0.102
D	8.90		9.90	0.350		0.390
E	9.90		10.3	0.39		0.406
F	6.30		6.90	0.248		0.272
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.39			0.133	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
φ		3.6			0.142	

Mechanical Dimensions DPAK



SYMBOL	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1	7°			7°		
V2	0°		6°	0°		6°

Ratings and Characteristics Curves

FIG.1: Maximum power dissipation versus RMS on-state current

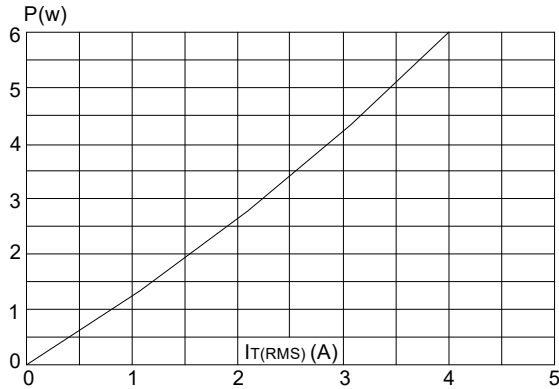


FIG.2: RMS on-state current versus case temperature

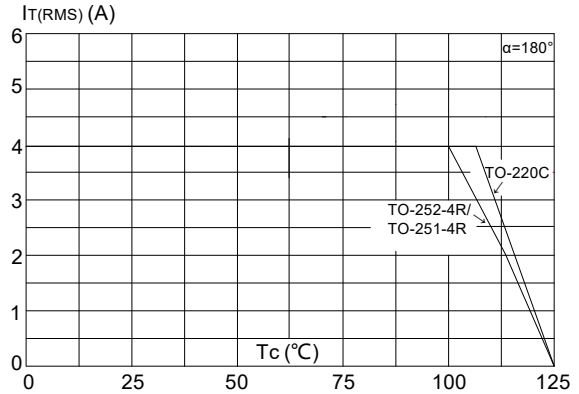


FIG.3: Surge peak on-state current versus number of cycles

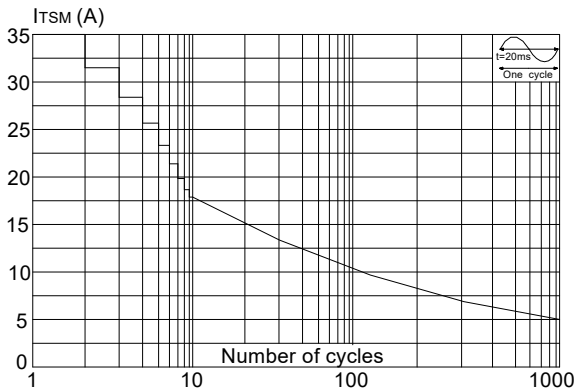


FIG.4: On-state characteristics (maximum values)

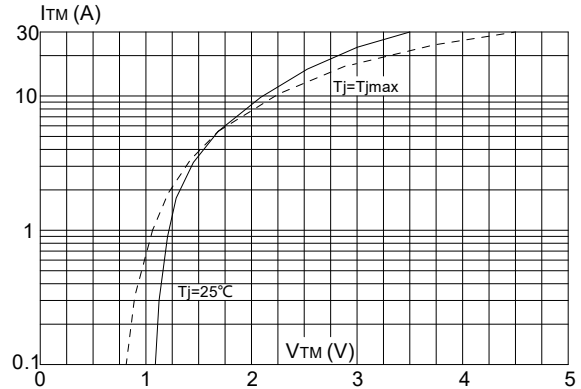


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20ms$ and corresponding value of I^2t (I - II - III: $dI/dt < 50A/\mu s$; IV: $dI/dt < 10A/\mu s$)

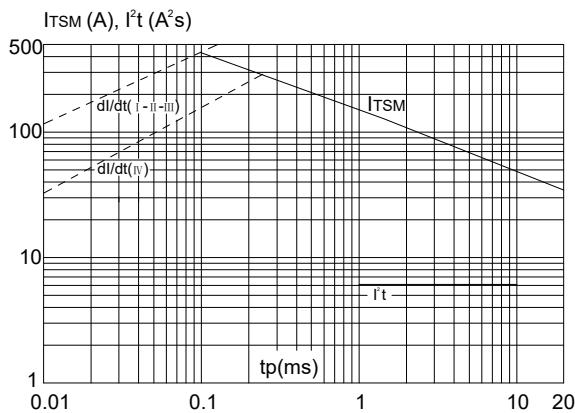
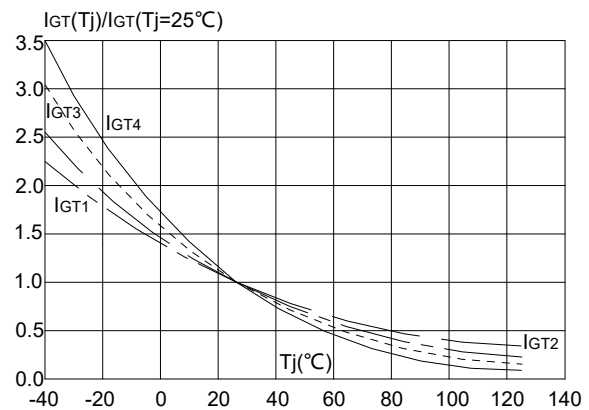


FIG.6: Relative variations of gate trigger current versus junction temperature



Technical Data
Data Sheet N2041, Rev.-



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